

SONY

CXL5005M/P

CMOS-CCD 1H Delay Line for NTSC with PLL

Description

The CXL5005M/P are general-purpose CCD delay line ICs which provide 1H delay time of NTSC.

Features

- Low power consumption 90mW (Typ.)
- Small size package (14-pin SOP, DIP)
- Low differential gain DG = 3% (Typ.)
- Input signal amplitude 180 IRE (= 1.28Vp-p, max.)
- Low input clock amplitude operation 200mVp-p (Min.)
- Built-in triple PLL circuit
- Built-in peripheral circuits (clock driver, timing generator, auto-bias and output circuits)

Functions

- 680-bit CCD register
- Clock drivers
- Autobias circuit
- Sync tip clamp circuit
- Sample-and-hold circuit
- PLL (triple)

Structure

CMOS-CCD

Absolute Maximum Ratings (Ta = 25°C)

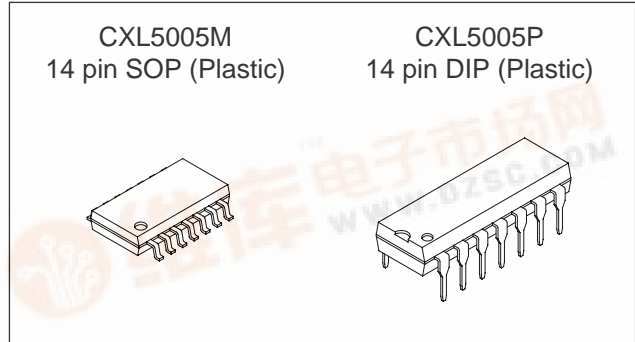
• Supply voltage	V _{DD}	11	V
• Supply voltage	V _{CL}	6	V
• Operating temperature	T _{opr}	-10 to +60	°C
• Storage temperature	T _{stg}	-55 to +150	°C
• Allowable power dissipation	P _D		
		CXL5005M	400 mW
		CXL5005P	800 mW

Recommended Operating Conditions

Supply voltage	V _{DD}	9 ± 5%	V
	V _{CL}	5 ± 5%	V

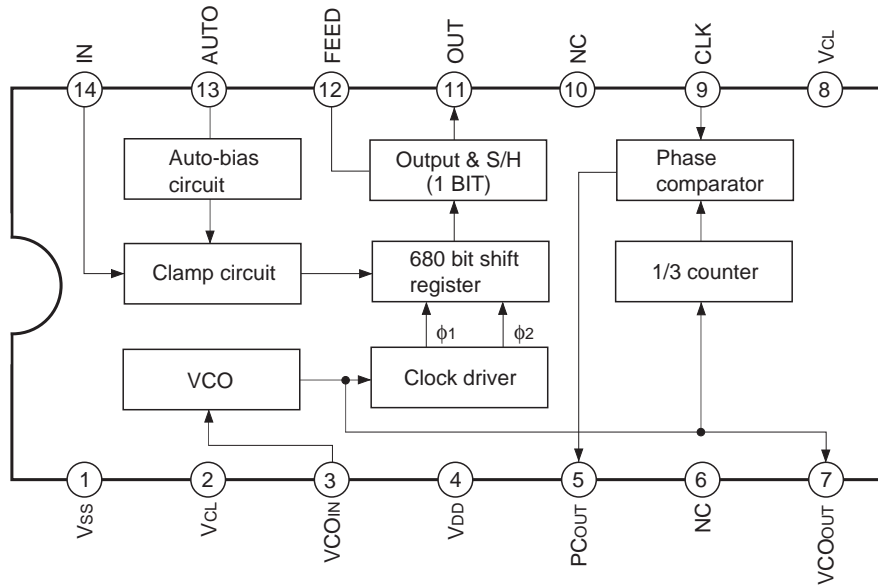
Recommended Clock Conditions

- Input clock amplitude V_{CLK} 200mVp-p to 1.0Vp-p (300mVp-p typ.)
- Clock frequency f_{CLK} 3.579545MHz



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Block Diagram and Pin configuration



Pin Description

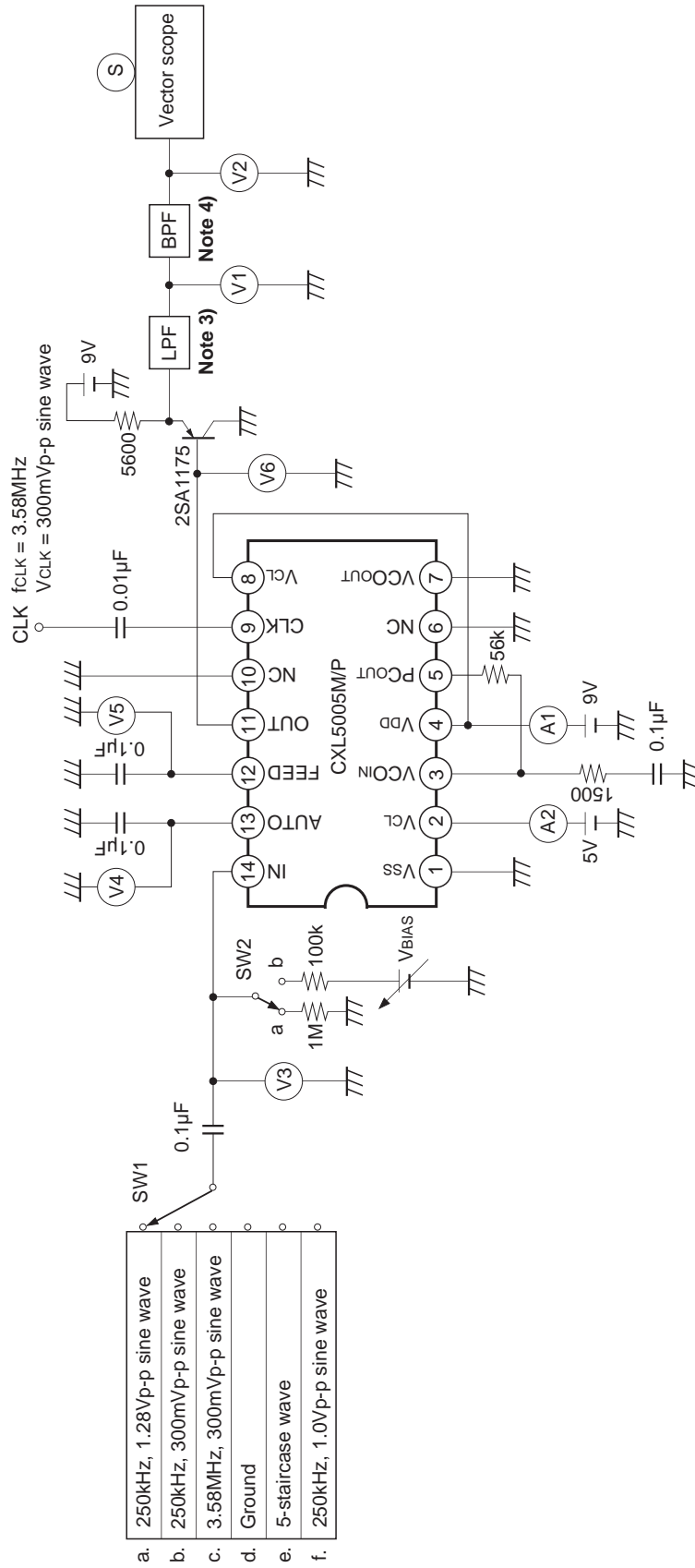
Pin No.	Symbol	Description	Impedance [Ω]
1	VSS	GND	
2	VCL	5V power supply	
3	VCO _{IN}	VCO input	> 100k
4	VDD	9V power supply	
5	PC _{OUT}	Phase comparator output	≈ 5k
6	NC		
7	VCO _{OUT}	VCO output	≈ 5k
8	VCL	5V power supply	
9	CLK	Clock input	≈ 5k
10	NC		
11	OUT	Signal output	600 to 1k
12	FEED	Feedback DC output	> 100k
13	AUTO	Autobias DC output	≈ 10k
14	IN	Signal input	> 100k

Electrical Characteristics

($T_a = 25^\circ\text{C}$, $V_{DD} = 9.0\text{V}$, $V_{CL} = 5.0\text{V}$, $f_{CLK} = 3.58\text{MHz}$, $V_{CLK} = 300\text{mVp-p}$ sine wave, See "Electrical Characteristics Test Circuit")

Item	Symbol	Test condition	SW condition		Measuring point	Min.	Typ.	Max.	Unit
			1	2					
Supply current	I _{DD}	250kHz, 1.28Vp-p, sine wave input	a	a	A1	—	4.0	5.0	mA
	I _{CL}				A2	—	9.0	12.0	mA
Insertion gain	IG	250kHz, 1.28Vp-p, sine wave input IG = 20 log (Output voltage [Vp-p] / 1.28 [Vp-p])	a	a	V1	-3.0	0.0	3.0	dB
Frequency response	fG	Dissipation at 3.58MHz in relation to 250kHz fG = 20 log (V _{3.58MHz} / V _{250kHz}) (Note 1)	b, c	b	V1	-3.0	-2.1	—	dB
Differential gain	DG	5-staircase wave input Y = 140 IRE (= 1.0Vp-p) Measure with vector scope (Note 2)	e	a	S	—	3.0	5.0	%
Differential phase	DP					—	3.0	5.0	deg
Allowable input amplitude	V _{IN-AC}		—	—	—	—	—	1.28	Vp-p
Noise	S/N	S: Input = 250kHz, 1.0Vp-p output (Vp-p)	f	a	V2	55	60	—	dB
		N: Input = DC GND output (V _{rms})	d	a					
DC output voltage	V _{IN-DC}		d	a	V3	3.5	5.0	6.5	V
	V _{AUTO-DC}				V4	3.5	5.0	6.5	V
	V _{FEED-DC}	250kHz, 1.28Vp-p, sine wave input	a	a	V5	1.3	2.3	3.3	V
	V _{OUT-DC}				V6	1.7	2.7	3.7	V

Electrical Characteristics Test Circuit

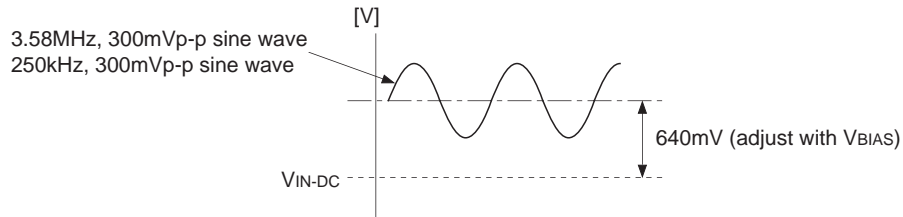


Note 1) Frequency response test condition

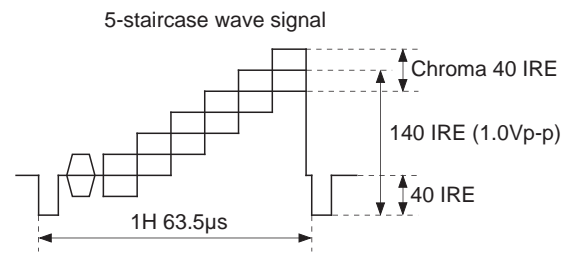
$V_{3.58\text{MHz}}$ (Output signal voltage [Vp-p] at 3.58MHz input)

$V_{250\text{kHz}}$ (Output signal voltage [Vp-p] at 250kHz input)

Set Pin 14 (IN) voltage [V] = $V_{\text{IN-DC}} + 640\text{mV}$.

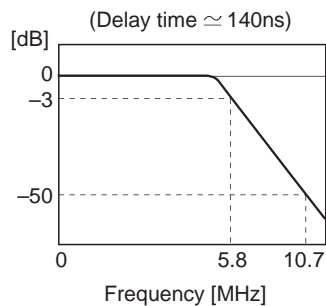


Note 2) Differential gain and differential phase test condition

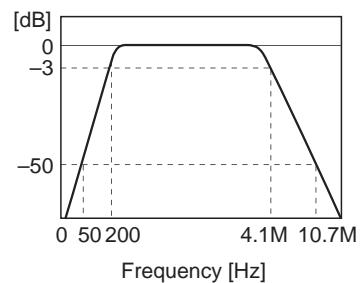


DG and DP are measured at output S point by vector scope.

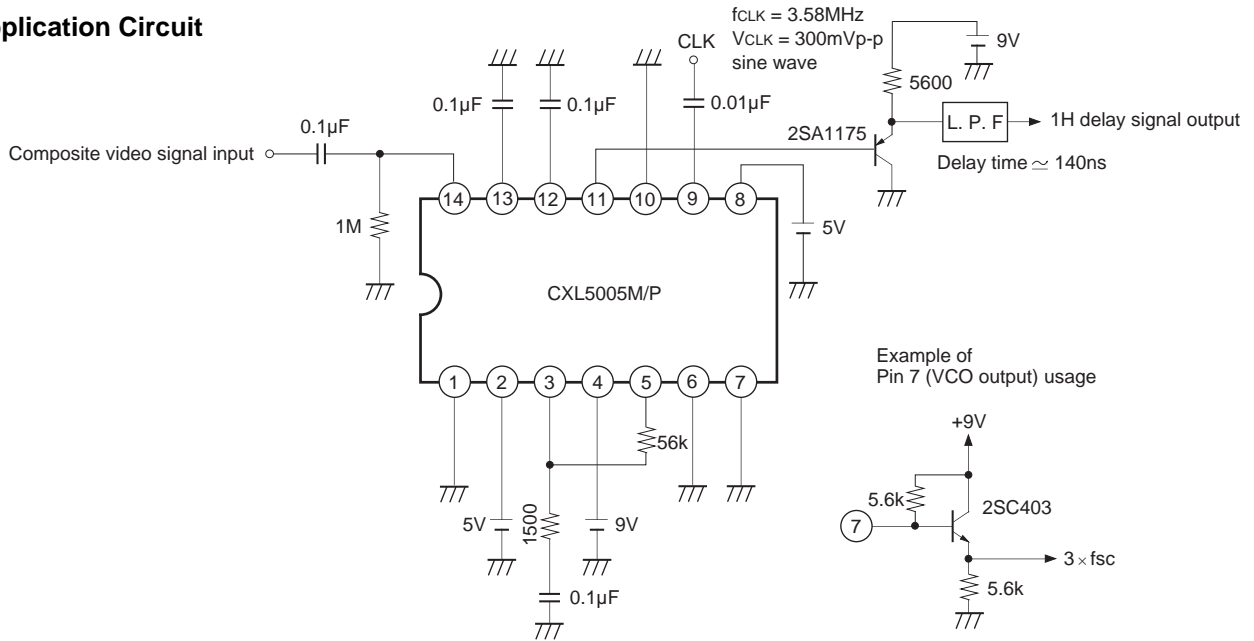
Note 3) LPF frequency response



Note 4) BPF frequency response

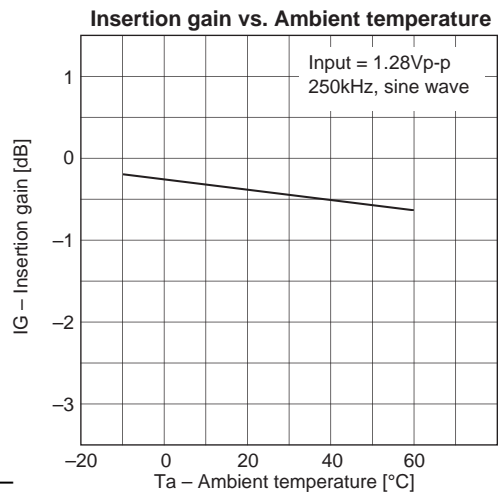
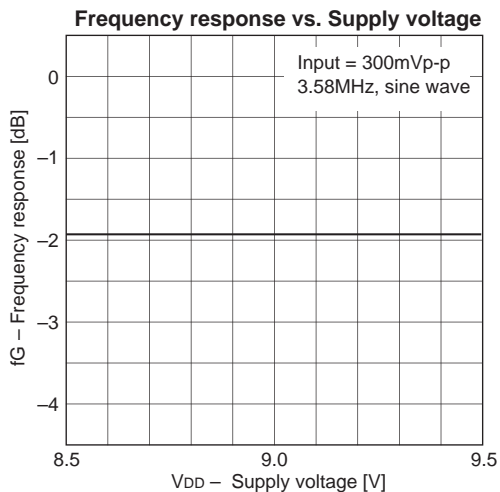
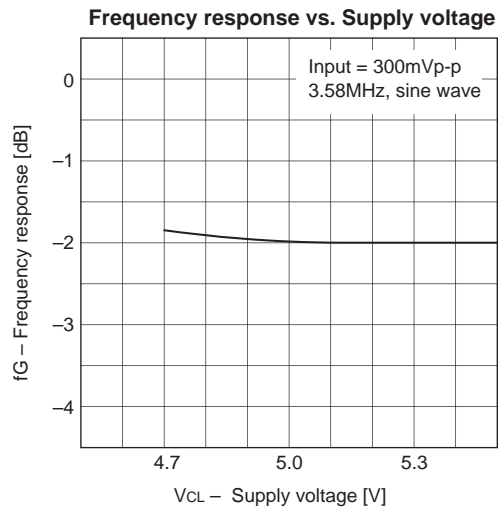
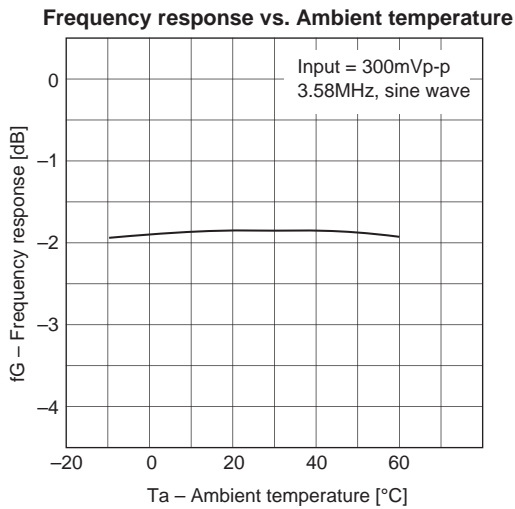


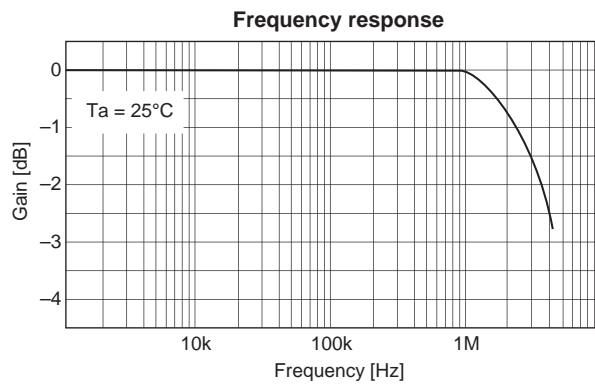
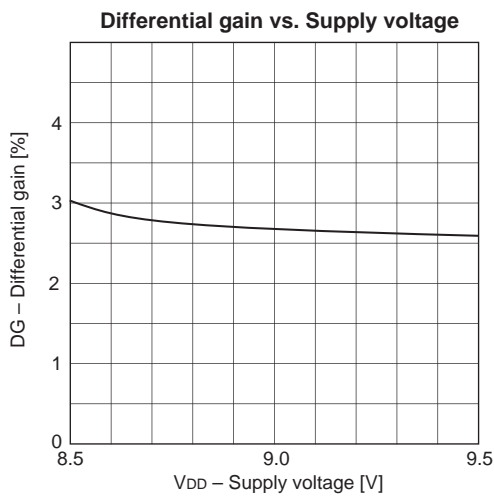
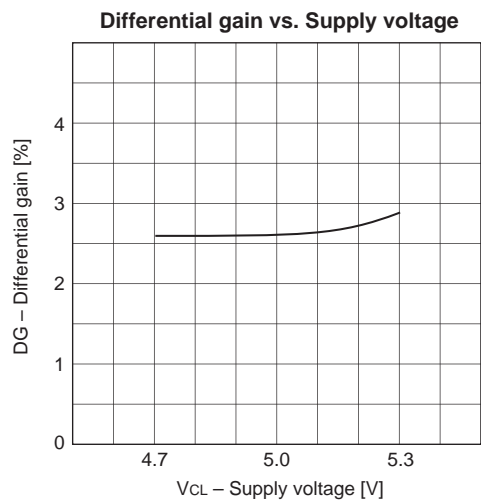
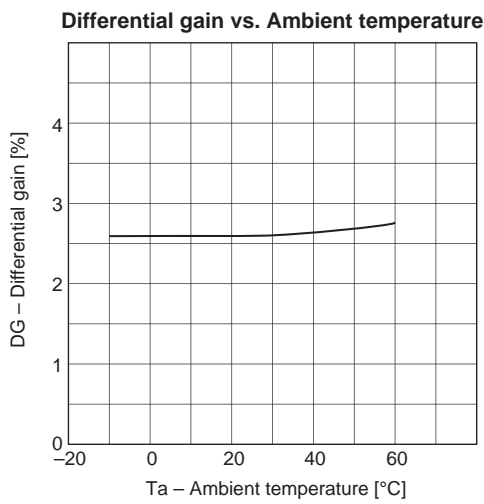
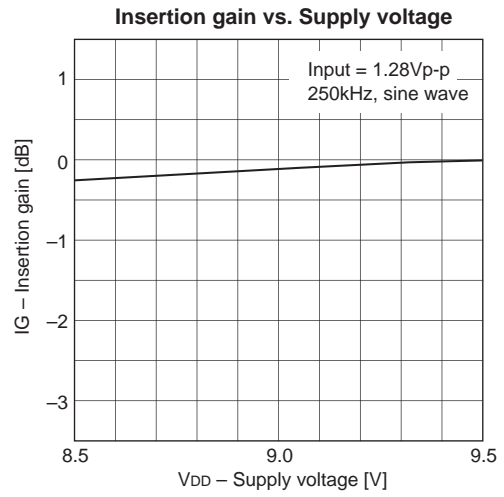
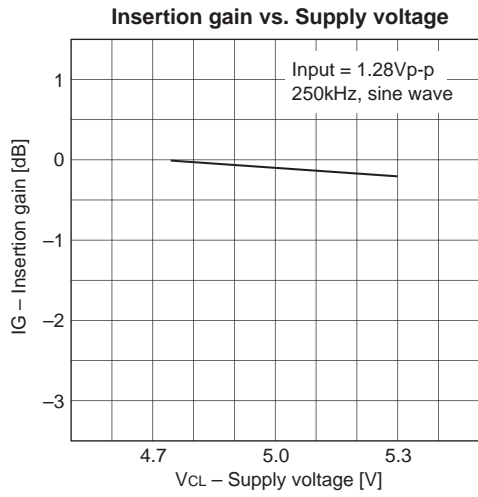
Application Circuit



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Example of Representative Characteristics

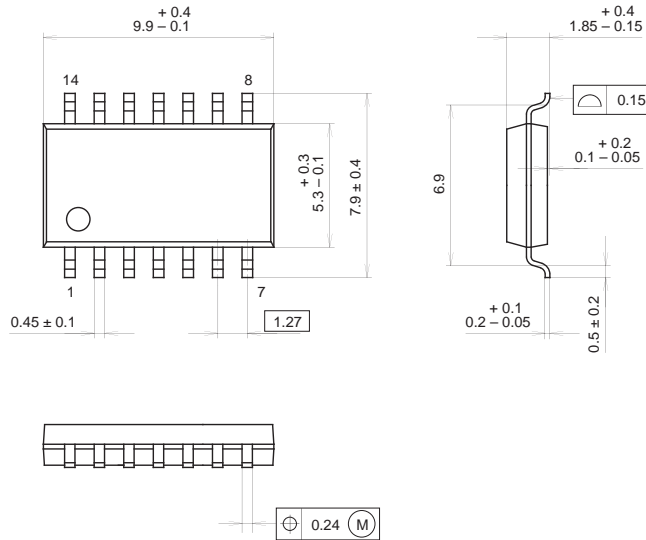




Package Outline Unit: mm

CXL5005M

14PIN SOP (PLASTIC)



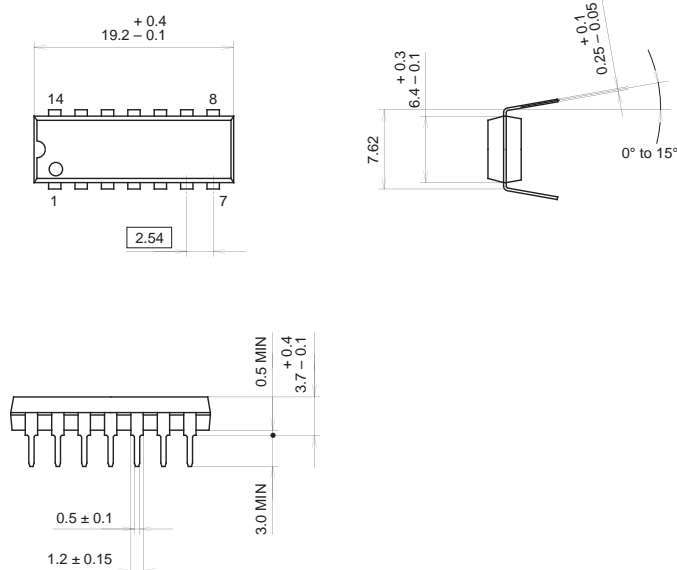
PACKAGE STRUCTURE

SONY CODE	SOP-14P-L01
EIAJ CODE	SOP014-P-0300
JEDEC CODE	—

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	42/COPPER ALLOY
PACKAGE MASS	0.2g

CXL5005P

14PIN DIP (PLASTIC)



PACKAGE STRUCTURE

SONY CODE	DIP-14P-01
EIAJ CODE	DIP014-P-0300
JEDEC CODE	Similar to MO-001-AH

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	42/COPPER ALLOY
PACKAGE MASS	0.9g